



Product Preview

1200V/150A HALF-BRIDGE MODULE WITH

FIELD-STOP TRENCH IGBT AND DIODE

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Features

• Low V_{CE(sat)}

Applications

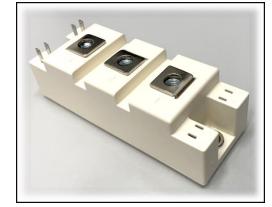
• Welding

- Fast Switching
- High Ruggedness
- Short-Circuit Rated

• General Purpose Inverters

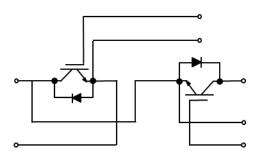
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Proc	duct Summary				
Vces	1200V				
lc 150A					
V _{CE(sat),typ} 2.0V (T _J = 25°C)					



Internal Connection

• Induction Heating



• IGBT, Inverter

Absolute Maximum Ratings

Parameter	Symbol	Limit	Unit
Collector-to-Emitter Voltage	V _{CES}	1200	v
Gate-to-Emitter Voltage	V _{GES}	±20	v
Continuous DC Collector Current	ICDC	150	
Repetitive Peak Collector Current	I _{CRM}	300	A
Maximum Power Dissipation ($T_c = 25^{\circ}C$, $T_J = 175^{\circ}C$)	P _{D(max)}	500	w

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Electrical Characteristics ^{(1), (2)}

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Collector-to-Emitter Breakdown Voltage	BV _{CES}	V _{GE} = 0V, I _C = 250μA	1200	-	-	V
Collector-to-Emitter Leakage Current	I _{CES}	V _{CE} = 1200V, V _{GE} = 0V	-	-	5	mA
Gate-to-Emitter Leakage Current	I _{GES}	$V_{CE} = 0V, V_{GE} = \pm 20V$	-	-	400	nA
Gate Threshold Voltage	V _{GE(th)}	$V_{CE} = V_{GE}$, $I_C = 1.5 mA$	5.5	6.5	7.5	
		V _{GE} = 15V, I _C = 150A	-	2.0	2.4	
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	V _{GE} = 15V, I _C = 150A, T _J =125°C	-	2.6	-	v
		V _{GE} = 15V, I _C = 150A, T _J =150°C	-	2.8	-	
Total Gate Charge	Qg	V _{CC} = 600V, V _{GE} = 0/15V, I _C = 150A	-	478	-	nC
Internal Gate Resistance	R _{Gint}	-	-	4.0	-	Ω
Input Capacitance	C _{iss}	V _{CE} = 25V,	-	9.6	-	
Output Capacitance	C _{oss}	V _{GE} = 0V,	-	0.4	-	nF
Reverse Transfer Capacitance	C _{rss}	f = 1MHz	-	0.1	-	
Turn-on Delay time	t _{d(ON)}		-	80	-	
Rise Time	t _r	V _{CC} = 600V, V _{GE} = 0/15V,	-	46	-	
Turn-off Delay time	t _{d(OFF)}	R _G = 2Ω, I _C = 150A,	-	290	-	ns
Fall Time	t _f	$L_{load} = 0.82 mH$,	-	118	-	
Turn-On Switching Loss	E _{on}	Energy losses include "tail" and diode reverse	-	5.8	-	
Turn-Off Switching Loss	E _{off}	recovery.	-	7.8	-	mJ
IGBT Total Switching Loss	E _{ts}		-	13.6	-	
Turn-on Delay time	t _{d(ON)}	N 600V	-	87	-	
Rise Time	t _r	V _{CC} = 600V, V _{GE} = 0/15V,	-	50	-	
Turn-off Delay time	t _{d(OFF)}	R _G = 2Ω, I _C = 150A,	-	330	-	ns
Fall Time	t _f	$L_{load} = 0.82 mH$,	-	137	-	
Turn-On Switching Loss	Eon	Energy losses include "tail" and diode reverse	-	11.5	-	
Turn-Off Switching Loss	E _{off}	recovery. TJ =150°C	-	10	-	mJ
IGBT Total Switching Loss	E _{ts}		-	21.5	-	
Short Circuit Collector Current	I _{C(SC)}	V_{GE} = 15V, $V_{CC} \le 600V$, $t_{SC} \le 10 \mu s$	-	350	-	A

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• Diode, Inverter

Absolute Maximum Ratings

Parameter	Symbol	Limit	Unit
Repetitive Peak Reverse Voltage	V _{RRM}	1200	v
Continuous DC Forward Current	I _F	150	
Repetitive Peak Forward Current	I _{FRM}	300	A

Electrical Characteristics (1)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Diode Forward Voltage		I _F = 150A	-	2.2	2.65	
	V _F	I _F = 150A T _J = 125°C	-	2.1	-	v
		I _F = 150A T _J = 150°C	-	2.05	-	
Diode Reverse-Recovery Charge	Q _{rr}		-	7.0	-	μC
Diode Peak Reverse-Recovery Current		V _R = 600V, I _F = 150A, dI _F /dt = -2630 A/μs	-	137	-	А
Diode Reverse-Recovery Loss	Err		-	2.7	-	mJ

• <u>Module</u>

Absolute Maximum Ratings

Parameter	Symbol	Symbol Limit	
Maximum Junction Temperature	Tj	-40 to +175	
Operating Junction Temperature	T _{vj op}	-40 to +150	°C
Storage Temperature	T _{stg}	-40 to +125	
Isolation Voltage (f = 50 Hz, t = 1 min)	V _{ISO}	2.5	kV

Characteristics

Parameter	Symbol	Min	Тур	Max	Unit
Material of Module Baseplate	-	-	Cu	-	-
Internal Isolation	-	-	AI_2O_3	-	-
Creepage Distance, Terminal to Heatsink	-	-	17	-	mm
Creepage Distance, Terminal to Terminal	-	-	20	-	mm

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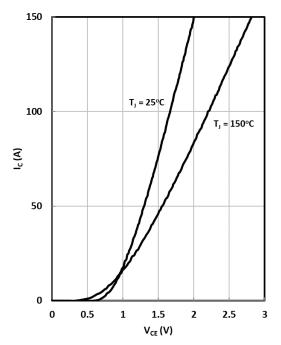
Clearance Terminal to Heatsink			17		
Clearance, Terminal to Heatsink	-	-	17	-	mm
Clearance, Terminal to Terminal	-	-	9.5	-	mm
Stray Inductance, Module	L _{SCE}	-	30	-	nH
Module Lead Resistance, Terminal to Chip	R _{CC'+EE'}	-	0.65	-	mΩ
Junction-to-Case Thermal Resistance, per IGBT, Inverter	R _{θJC}	-	0.24	-	°C/W
Junction-to-Case Thermal Resistance, per Diode, Inverter		-	0.46	-	
Case-to-Heatsink Thermal Resistance, per IGBT, Inverter		-	0.08	-	
Case-to-Heatsink Thermal Resistance, per Diode, Inverter	R _{0CH}	-	0.15	-	°C/W
Case-to-Heatsink Thermal Resistance, per Module		-	0.05	-	
Mounting Torque for Module Mounting, Screw M6	М	3.0	-	5.0	Nm
Terminal Connection Torque, Screw M6	м	2.5	-	5.0	Nm
Weight per Module	G	-	160	-	g

(1) $T_J = 25^{\circ}C$ unless otherwise specified

(2) $t_r:$ from 10% of Ic to 90% of Ic; $t_f:$ from 90% of Ic to 10% of Ic;

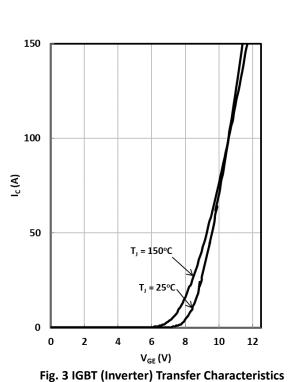
 $E_{on}\!\!:$ from 10% of V_{GE} to 10% of $V_{CE}\!\!:$ $E_{off}\!\!:$ from 90% of V_{GE} to 10% of Ic.





• **Typical Electrical Characteristics**

Fig. 1 IGBT (Inverter) Output Characteristics



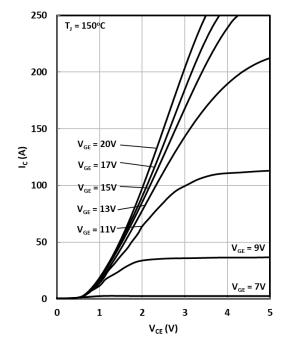
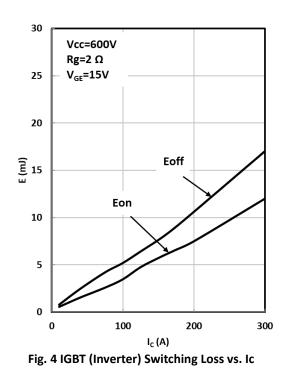


Fig. 2 IGBT (Inverter) Output Characteristics



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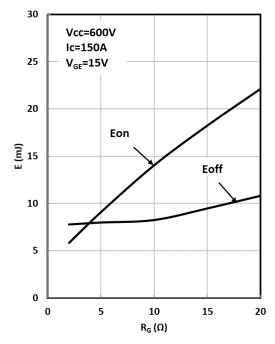


Fig. 5 IGBT (Inverter) Switching Loss vs. Rg

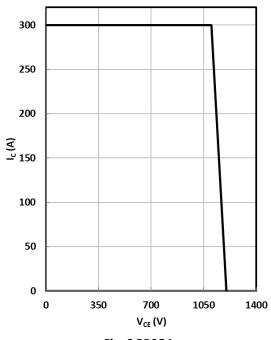
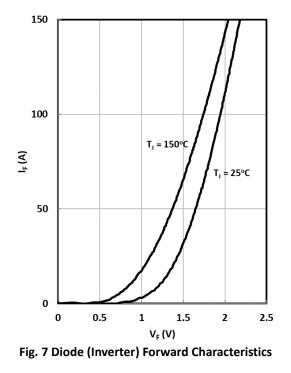
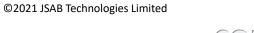


Fig. 6 RBSOA



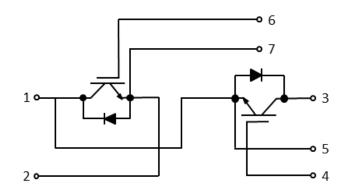


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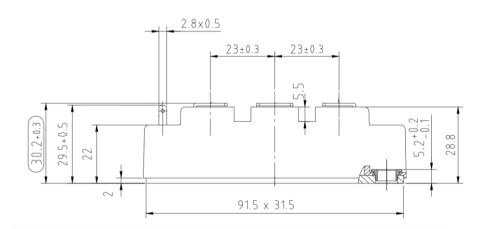
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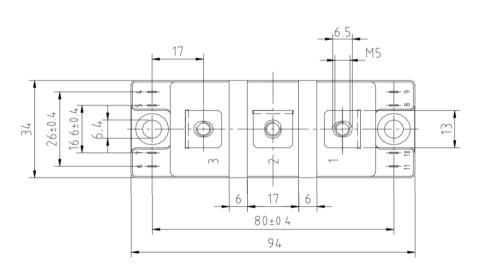


• <u>Circuit diagram</u>



Package Dimensions







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